

March 1997

### Features

- Performs Memory Address Latch and Decoder Functions Multiplexed or Non-Multiplexed
- Interfaces Directly with the CDP1800-Series Microprocessors
- Allows Decoding for Systems Up to 32K Bytes

### Ordering Information

5V	10V	TEMP. RANGE	PACKAGE	PKG. NO.
CDP1883CE	CDP1883E	-40°C to +85°C	PDIP	E20.3

### Description

The CDP1883 is a CMOS 7-bit memory latch and decoder circuit intended for use in CDP1800-series microprocessor systems. It can serve as a direct interface between the multiplexed address bus of this system and up to four 8K x 8-bit memories to implement a 32K-byte memory system. With four 4K x 8-bit memories, a 16K-byte system can be decoded.

The device is also compatible with non-multiplexed address bus microprocessors. By connecting the clock input to  $V_{DD}$ , the latches are in the data-following mode and the decoded outputs can be used in general-purpose memory-system applications.

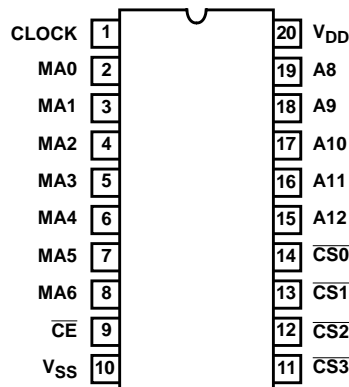
The CDP1883 is compatible with CDP1800-series microprocessors operating at maximum clock frequency.

The CDP1883 and CDP1883C are functionally identical. They differ in that the CDP1883 has a recommended operating voltage range of 4V to 10.5V and the C version has a recommended operating voltage range of 4V to 6.5V.

The CDP1883 and CDP1883C are supplied in 20 lead dual-in-line plastic packages (E Suffix).

### Pinout

CDP1883, CDP1883C  
(PDIP)  
TOP VIEW



# CDP1883, CDP1883C

## Absolute Maximum Ratings

DC Supply Voltage Range, ( $V_{DD}$ ) (All Voltages Referenced to $V_{SS}$ Terminal)	
CDP1883	-0.5V to +11V
CDP1883C	-0.5V to +7V
Input Voltage Range, All Inputs	-0.5V to $V_{DD} + 0.5V$
DC Input Current, Any One Input	$\pm 10mA$

## Thermal Information

Thermal Resistance (Typical)	$\theta_{JA}$ ( $^{\circ}C/W$ )
PDIP Package	80
Device Dissipation Per Output Transistor	
$T_A$ = Full Package Temperature Range	100mW
Operating Temperature Range ( $T_A$ )	
Package Type E	-40 $^{\circ}C$ to +85 $^{\circ}C$
Storage Temperature Range ( $T_{STG}$ )	-65 $^{\circ}C$ to +150 $^{\circ}C$
Lead Temperature (During Soldering)	
At distance 1/16 $\pm$ 1/32 In. (1.59 $\pm$ 0.79mm)	
from case for 10s max	+265 $^{\circ}C$

*CAUTION: Stresses above those listed in the "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operation section of this specification is not implied.*

## Recommended Operating Conditions

At  $T_A$  = Full Package Temperature Range. For maximum reliability, operating conditions should be selected so that operation is always within the following ranges:

PARAMETER	SYMBOL	CDP1883		CDP1883C		UNITS
		MIN	MAX	MIN	MAX	
DC Operating Voltage Range		4	10.5	4	6.5	V
Input Voltage Range		$V_{SS}$	$V_{DD}$	$V_{SS}$	$V_{DD}$	V

## Static Electrical Specifications

At  $T_A$  = -40 $^{\circ}C$  to +85 $^{\circ}C$ ,  $V_{DD} \pm 5\%$ , Except as Noted:

PARAMETER	SYMBOL	CONDITIONS			CDP1883			CDP1883C			UNITS
		$V_O$ (V)	$V_{IN}$ (V)	$V_{DD}$ (V)	MIN	(NOTE 1) TYP	MAX	MIN	(NOTE 1) TYP	MAX	
Quiescent Device Current	$I_{DD}$	-	0, 5	5	-	1	10	-	5	50	$\mu A$
		-	0, 10	10	-	10	100	-	-	-	$\mu A$
Output Low Drive (Sink) Current	$I_{OL}$	0.4	0, 5	5	1.6	3.2	-	1.6	3.2	-	mA
		0.5	0, 10	10	3.2	6.4	-	-	-	-	mA
Output High Drive (Source) Current	$I_{OH}$	4.6	0, 5	5	-1.15	-2.3	-	-1.15	-2.3	-	mA
		9.5	0, 10	10	-2.3	-4.6	-	-	-	-	mA
Output Voltage Low-Level (Note 2)	$V_{OL}$	-	0, 5	5	-	0	0.1	-	0	0.1	V
		-	0, 10	10	-	0	0.1	-	-	-	V
Output Voltage High-Level (Note 2)	$V_{OH}$	-	0, 5	5	4.9	5	-	4.9	5	-	V
		-	0, 10	10	9.9	10	-	-	-	-	V
Input Low Voltage	$V_{IL}$	0.5, 4.5	-	5	-	-	1.5	-	-	1.5	V
		0.5, 9.5	-	10	-	-	3	-	-	-	V
Input High Voltage	$V_{IH}$	0.5, 4.5	-	5	3.5	-	-	3.5	-	-	V
		0.5, 9.5	-	10	7	-	-	-	-	-	V
Input Leakage Current	$I_{IN}$	Any Input	0, 5	5	-	-	$\pm 1$	-	-	$\pm 1$	$\mu A$
			0, 10	10	-	-	$\pm 2$	-	-	-	$\mu A$
Operating Current (Note 3)	$I_{DD1}$	0, 5	0, 5	5	-	-	2	-	-	2	mA
		0, 10	0, 10	10	-	-	4	-	-	-	mA

# CDP1883, CDP1883C

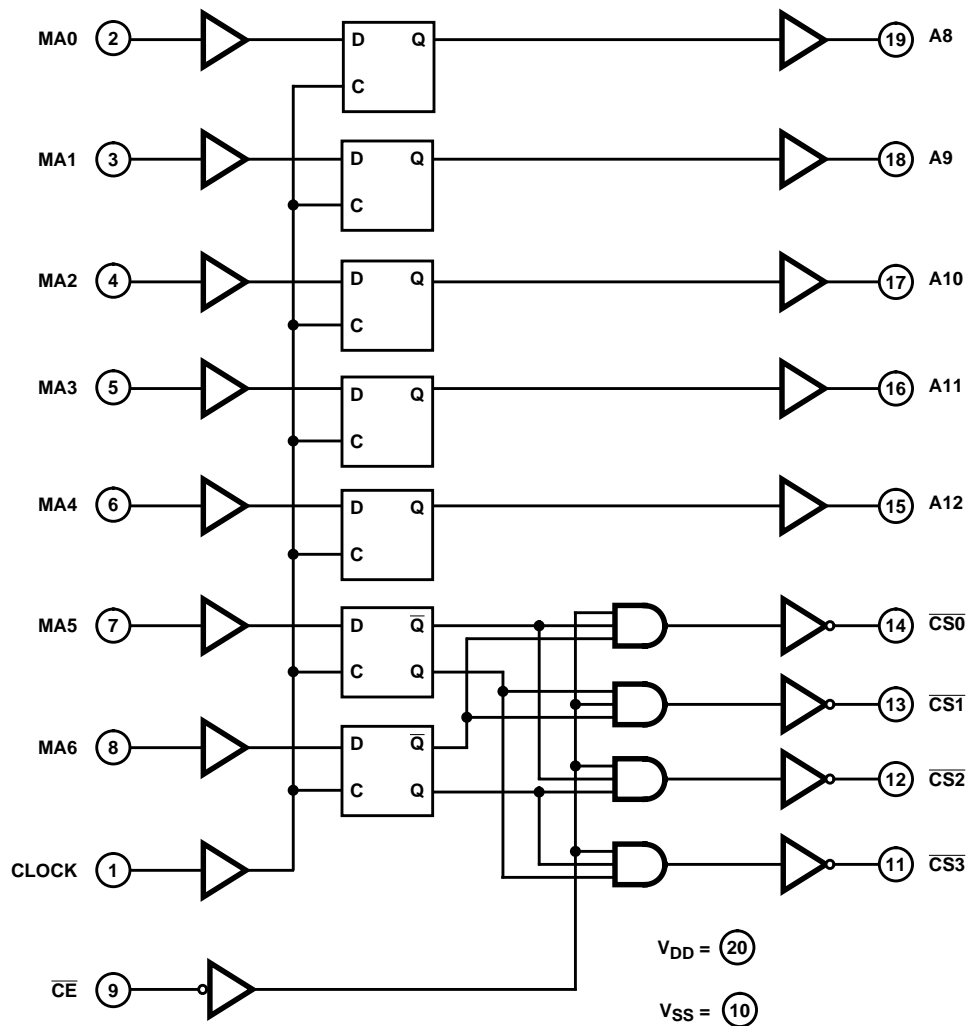
**Static Electrical Specifications** At  $T_A = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ ,  $V_{DD} \pm 5\%$ , Except as Noted: (Continued)

PARAMETER	SYMBOL	CONDITIONS			CDP1883			CDP1883C			UNITS
		$V_O$ (V)	$V_{IN}$ (V)	$V_{DD}$ (V)	MIN	(NOTE 1) TYP	MAX	MIN	(NOTE 1) TYP	MAX	
Minimum Data Retention Voltage	$V_{DR}$	$V_{DD} = V_{DR}$			-	2	2.4	-	2	2.4	V
Data Retention Current	$I_{DR}$	$V_{DD} = 2.4\text{V}$			-	0.01	1	-	0.5	5	$\mu\text{A}$
Input Capacitance	$C_{IN}$	-	-	-	-	5	7.5	-	5	7.5	pF
Output Capacitance	$C_{OUT}$	-	-	-	-	10	15	-	10	15	pF

**NOTES:**

1. Typical values are for  $T_A = +25^{\circ}\text{C}$ .
2.  $I_{OL} = I_{OH} = \mu\text{A}$
3. Operating current measured at 200kHz for  $V_{DD} = 5\text{V}$  and 400kHz for  $V_{DD} = 10\text{V}$ , with outputs open circuit.

## Functional Diagram



**Signal Descriptions/Pin Functions**

**CLOCK:** Latch Input Control - a high on the clock input will allow data to pass through the latch to the output pin. Data is latched on the high-to-low transition of the clock input. This pin is connected to TPA in CDP1800-series systems and tied to V<sub>DD</sub> for other applications.

**MA0 - MA4:** Address inputs to the high-byte address latches.

**MA5 - MA6:** High byte address inputs decoded to produce chip selects  $\overline{CS0}$  -  $\overline{CS3}$ .

**$\overline{CE}$ :** CHIP ENABLE input - A low on this pin will enable the chip select decoder. A high on this pin forces  $\overline{CS0}$ ,  $\overline{CS1}$ ,  $\overline{CS2}$ , and  $\overline{CS3}$  outputs to a high (false) state.

**A8 - A12:** Latched high-byte address outputs.

**$\overline{CS0}$  -  $\overline{CS3}$ :** One of four latched and decoded Chip Select outputs.

**V<sub>DD</sub>, V<sub>SS</sub>:** Power and ground pins, respectively.

TRUTH TABLE

INPUTS				OUTPUTS			
$\overline{CE}$	CLK	MA5	MA6	$\overline{CS0}$	$\overline{CS1}$	$\overline{CS2}$	$\overline{CS3}$
0	1	0	0	0	1	1	1
0	1	1	0	1	0	1	1
0	1	0	1	1	1	0	1
0	1	1	1	1	1	1	0
0	0	X	X	Previous State			
1	X	X	X	1	1	1	1

**Dynamic Electrical Specifications** T<sub>A</sub> = -40°C to +85°C, V<sub>DD</sub> ± 5%, t<sub>R</sub>, t<sub>F</sub> = 20ns, V<sub>IH</sub> = 0.7 V<sub>DD</sub>, V<sub>IL</sub> = 0.3 V<sub>DD</sub>, C<sub>L</sub> = 100pF. See Figure 1

PARAMETER	V <sub>DD</sub> (V)	CDP1883			CDP1883C			UNITS	
		MIN	(NOTE 1) TYP	(NOTE 2) MAX	MIN	(NOTE 1) TYP	(NOTE 2) MAX		
Minimum Setup Time, Memory Address to CLOCK	t <sub>MACL</sub>	5	-	10	35	-	10	35	ns
		10	-	8	25	-	-	-	ns
Minimum Hold Time, Memory Address After CLOCK	t <sub>CLMA</sub>	5	-	8	25	-	8	25	ns
		10	-	8	25	-	-	-	ns
Minimum CLOCK Pulse Width	t <sub>CLCL</sub>	5	-	50	75	-	50	75	ns
		10	-	25	40	-	-	-	ns
PROPAGATION DELAY TIMES									
$\overline{\text{Chip Enable}}$ to $\overline{\text{Chip Select}}$	t <sub>CECS</sub>	5	-	75	150	-	75	150	ns
		10	-	45	100	-	-	-	ns
CLOCK to $\overline{\text{Chip Select}}$	t <sub>CLCS</sub>	5	-	100	175	-	100	175	ns
		10	-	65	125	-	-	-	ns

TRUTH TABLE

INPUTS			OUTPUTS
$\overline{CE}$	CLK	MA0 - 4	A8 - A12
X	1	1	1
X	1	0	0
X	0	X	Previous State

X = Don't Care

**Application Information**

The CDP1883 and CDP1883C can be interfaced, without external components, with CDP1800-series microprocessor systems. These microprocessors feature a multiplexed address bus and provide an address latch signal (TPA) that is used as the clock input of the CDP1883. See Figure 2 and Figure 3.

This signal is used to latch 7 bits of the high-order address. The lower five high-order address inputs are latched and held to be used with the eight lower-order address inputs to access an 8K x 8-bit memory. The two upper high-order address inputs are latched and decoded for use as chip selects.

The latched address and decoding functions of the CDP1883 and CDP1883C allow them to operate with 32K-byte memory systems. In addition, smaller memory systems can be configured with 4K x 8-bit or smaller memories, or a mix of memory sizes up to 8K x 8-bit.

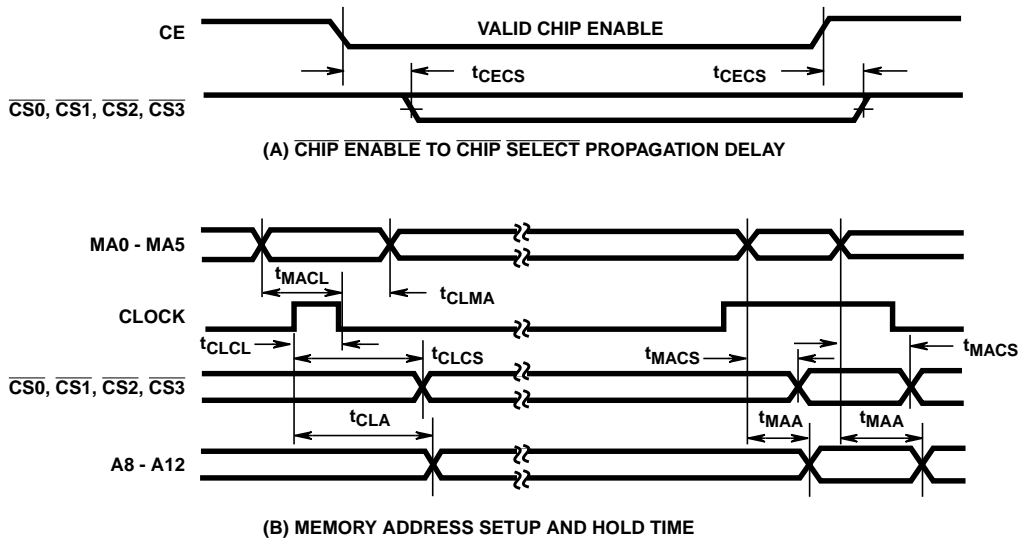
## CDP1883, CDP1883C

**Dynamic Electrical Specifications**  $T_A = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ ,  $V_{DD} \pm 5\%$ ,  $t_R, t_F = 20\text{ns}$ ,  $V_{IH} = 0.7 V_{DD}$ ,  $V_{IL} = 0.3 V_{DD}$ ,  $C_L = 100\text{pF}$ .  
See Figure 1 (Continued)

PARAMETER		$V_{DD}$ (V)	CDP1883			CDP1883C			UNITS
			MIN	(NOTE 1) TYP	(NOTE 2) MAX	MIN	(NOTE 1) TYP	(NOTE 2) MAX	
CLOCK to Address	$t_{CLA}$	5	-	100	175	-	100	175	ns
		10	-	65	125	-	-	-	ns
Memory Address to $\overline{\text{Chip Select}}$	$t_{MACS}$	5	-	100	175	-	100	175	ns
		10	-	75	125	-	-	-	ns
Memory Address to Address	$t_{MAA}$	5	-	80	125	-	80	125	ns
		10	-	40	60	-	-	-	ns

**NOTES:**

1. Typical values are for  $T_A = 25^{\circ}\text{C}$ .
2. Maximum limits of minimum characteristics are the values above which all devices function.



**FIGURE 1. CDP1883 TIMING WAVEFORMS**

All Intersil semiconductor products are manufactured, assembled and tested under **ISO9000** quality systems certification.

*Intersil products are sold by description only. Intersil Corporation reserves the right to make changes in circuit design and/or specifications at any time without notice. Accordingly, the reader is cautioned to verify that data sheets are current before placing orders. Information furnished by Intersil is believed to be accurate and reliable. However, no responsibility is assumed by Intersil or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Intersil or its subsidiaries.*

For information regarding Intersil Corporation and its products, see web site <http://www.intersil.com>

## CDP1883, CDP1883C

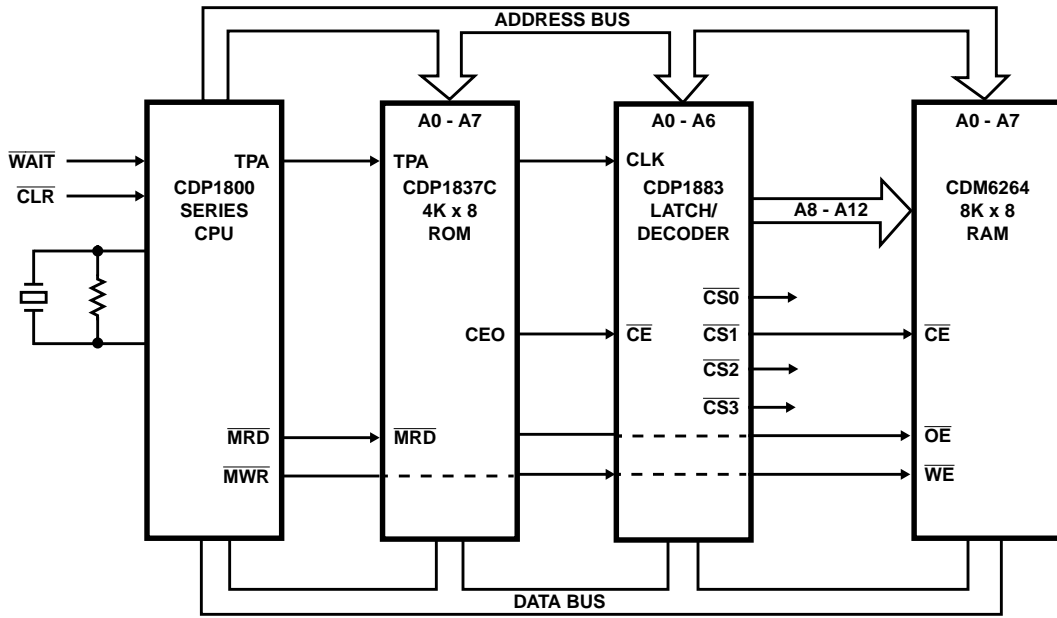


FIGURE 2. MINIMUM CDP1800-SYSTEM USING THE CDP1883 INTERFACE WITH AN 8K X 8-BIT MEMORY

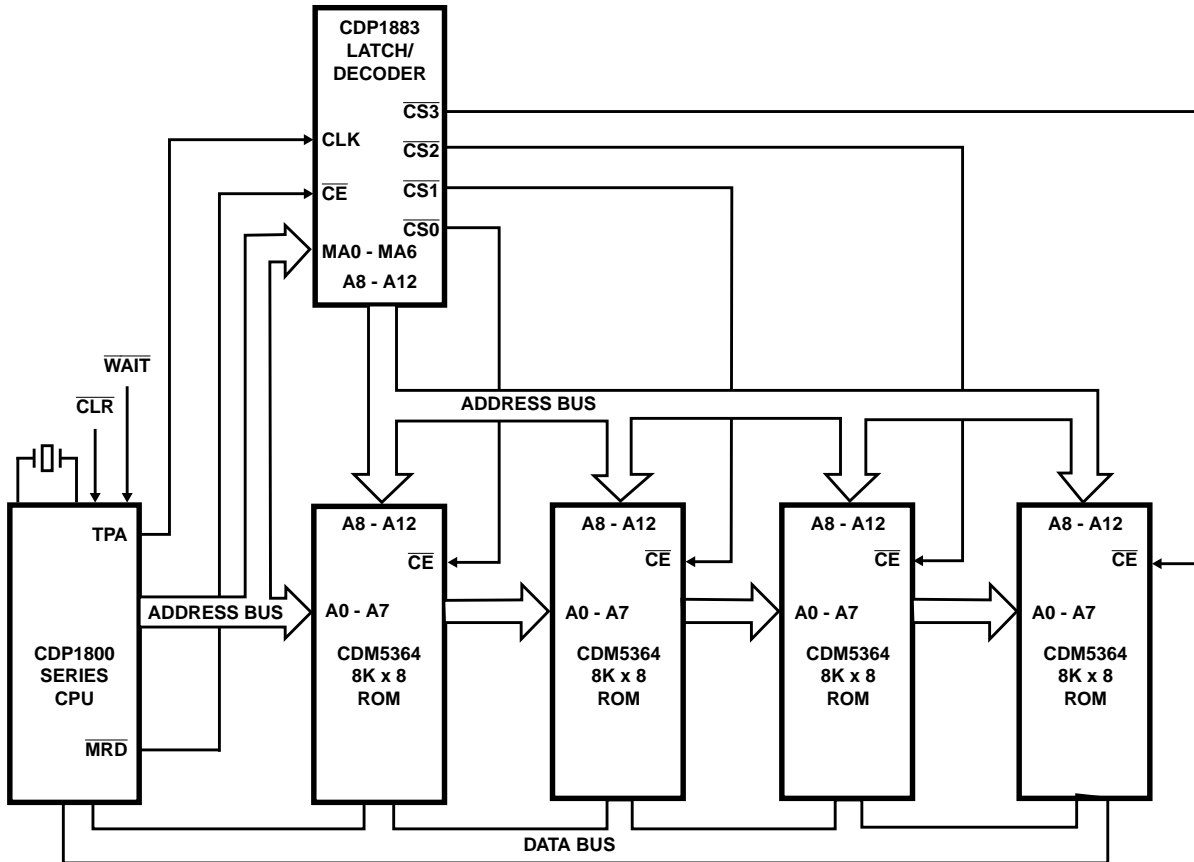


FIGURE 3. 32K-BYTE ROM SYSTEM USING THE CDP1883